

# Diang Xing

## List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/10416677/publications.pdf>

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4  
papers

30  
citations

3311381

1  
h-index

3475538

1  
g-index

4  
all docs

4  
docs citations

4  
times ranked

12  
citing authors

#	ARTICLE	IF	CITATIONS
1	Comparative Study of 6.5 kV 4H-SiC Discrete Packaged MOSFET, JBSFET, and Co-Pack (MOSFET and JBS) Tj ETQq1 1 0.784314 rgBT / Ov	10.784314	14
2	The Road to a Robust and Affordable SiC Power MOSFET Technology. Energies, 2021, 14, 8283.	3.1	10
3	Gate Oxide Reliability Studies of Commercial 1.2 kV 4H-SiC Power MOSFETs. , 2020, , .		12
4	Threshold Voltage Instability of Commercial 1.2 kV SiC Power MOSFETs. , 2020, , .		8